

Chip Termination 150 Watts, 50Ω

Description

The A150N50X4B is high performance Aluminum Nitride (AIN) chip termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power combiners. The termination is also RoHS compliant!

General Specifications

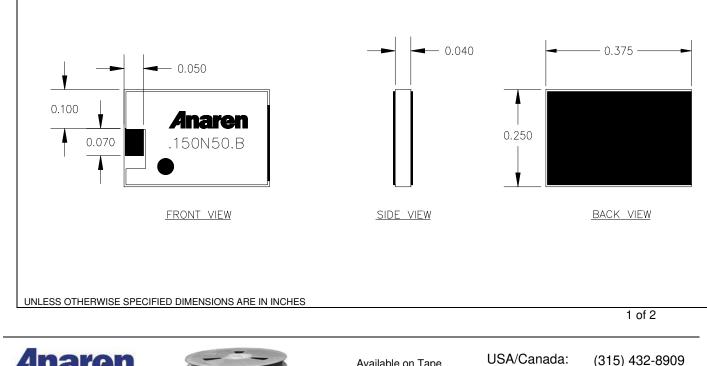
Resistive Element	Thick film
Substrate	AIN Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-55 to +200°C (see de rating chart)

Tolerance is $\pm 0.010"$, unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions in inches.

Electrical Specifications

Resistance Value:	50 Ohms, ± 2%
Power:	150 Watts
Frequency Range:	DC – 2.7 GHz
Return Loss	>26dB to 2.0 GHz >20dB to 2.7 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**





Features:

- RoHS Compliant
- 150 Watts
- DC 2.7 GHz
- AIN Ceramic
- Non-Nichrome Resistive
 Element
- Low VSWR
- 100% Tested

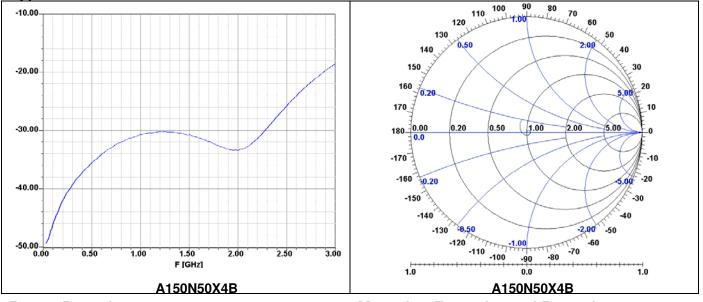
Outline Drawing



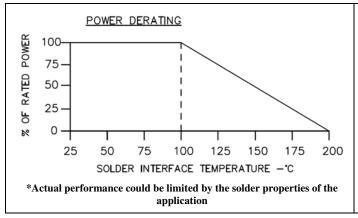
Available on Tape and Reel For Pick and Place Manufacturing. Toll Free: (800) 544-2414 Europe: +44 2392-232392

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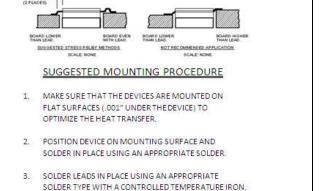
Typical Performance:



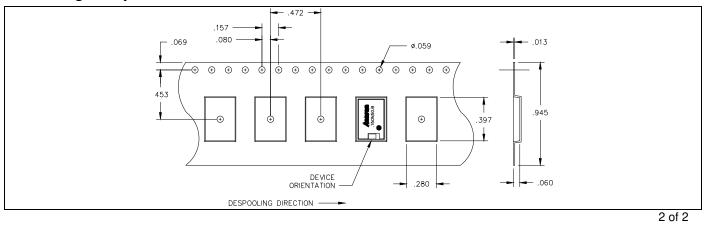
Power De-rating:



Mounting Footprint and Procedure:



Mounting Footprint and Procedure:



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